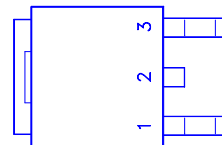
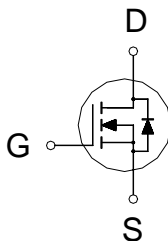


PRODUCT SUMMARY

| | | |
|---------------|--------------|-------|
| $V_{(BR)DSS}$ | $R_{DS(ON)}$ | I_D |
| 60 | 55m | 10A |



1.GATE
2.DRAIN
3.SOURCE

ABSOLUTE MAXIMUM RATINGS ($T_C = 25\text{ }^{\circ}\text{C}$ Unless Otherwise Noted)

| PARAMETERS/TEST CONDITIONS | | SYMBOL | LIMITS | UNITS |
|--|------------------------------------|----------------|------------|--------------------|
| Drain-Source Voltage | | V_{DS} | 60 | V |
| Gate-Source Voltage | | V_{GS} | ± 20 | V |
| Continuous Drain Current | $T_C = 25\text{ }^{\circ}\text{C}$ | I_D | 10 | A |
| | $T_C = 70\text{ }^{\circ}\text{C}$ | | 8 | |
| Pulsed Drain Current ¹ | | I_{DM} | 32 | |
| Power Dissipation | $T_C = 25\text{ }^{\circ}\text{C}$ | P_D | 32 | W |
| | $T_C = 70\text{ }^{\circ}\text{C}$ | | 22 | |
| Operating Junction & Storage Temperature Range | | T_J, T_{stg} | -55 to 150 | $^{\circ}\text{C}$ |
| Lead Temperature (¹ / ₁₆ " from case for 10 sec.) | | T_L | 275 | |

THERMAL RESISTANCE RATINGS

| THERMAL RESISTANCE | SYMBOL | TYPICAL | MAXIMUM | UNITS |
|---------------------|-----------------|---------|---------|-------------------------------|
| Junction-to-Case | $R_{\theta JC}$ | | 3 | $^{\circ}\text{C} / \text{W}$ |
| Junction-to-Ambient | $R_{\theta JA}$ | | 75 | $^{\circ}\text{C} / \text{W}$ |

¹Pulse width limited by maximum junction temperature.

²Duty cycle $\leq 1\%$

ELECTRICAL CHARACTERISTICS ($T_C = 25\text{ }^{\circ}\text{C}$, Unless Otherwise Noted)

| PARAMETER | SYMBOL | TEST CONDITIONS | LIMITS | | | UNIT |
|---------------------------------|---------------|--|--------|-----|-----------|---------|
| | | | MIN | TYP | MAX | |
| STATIC | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(BR)DSS}$ | $V_{GS} = 0V, I_D = 250\mu A$ | 60 | | | V |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = 250\mu A$ | 1 | 1.5 | 2.5 | |
| Gate-Body Leakage | I_{GSS} | $V_{DS} = 0V, V_{GS} = \pm 20V$ | | | ± 250 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 48V, V_{GS} = 0V$ | | | 1 | μA |
| | | $V_{DS} = 40V, V_{GS} = 0V, T_J = 55\text{ }^{\circ}C$ | | | 10 | |

| | | | | | | |
|--|--------------|-----------------------------|----|----|----|---|
| On-State Drain Current ¹ | $I_{D(ON)}$ | $V_{DS} = 5V, V_{GS} = 10V$ | 32 | | | A |
| Drain-Source Resistance ¹ On-State | $R_{DS(ON)}$ | $V_{GS} = 4.5V, I_D = 8A$ | | 59 | 75 | m |
| | | $V_{GS} = 10V, I_D = 10A$ | | 42 | 55 | |
| Forward Transconductance ¹ | g_{fs} | $V_{DS} = 10V, I_D = 10A$ | | 14 | | S |

DYNAMIC

| | | | | | | | |
|----------------------------------|--------------|---|--|--|------|----|----|
| Input Capacitance | C_{iss} | $V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$ | | | 650 | | pF |
| Output Capacitance | C_{oss} | | | | 80 | | |
| Reverse Transfer Capacitance | C_{rss} | | | | 35 | | |
| Total Gate Charge ² | Q_g | $V_{DS} = 0.5V_{(BR)DSS}, V_{GS} = 10V,$ $I_D = 4.5A$ | | | 12.5 | 18 | nC |
| Gate-Source Charge ² | Q_{gs} | | | | 2.4 | | |
| Gate-Drain Charge ² | Q_{gd} | | | | 2.6 | | |
| Turn-On Delay Time ² | $t_{d(on)}$ | $V_{DD} = 30V$ $I_D \cong 1A, V_{GS} = 10V, R_{GEN} = 6$ | | | 11 | 20 | nS |
| Rise Time ² | t_r | | | | 8 | 18 | |
| Turn-Off Delay Time ² | $t_{d(off)}$ | | | | 19 | 35 | |
| Fall Time ² | t_f | | | | 6 | 15 | |

SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ($T_c = 25^\circ C$)

| | | | | | | |
|------------------------------|----------|-------------------------|--|--|-----|---|
| Continuous Current | I_S | | | | 1.3 | A |
| Pulsed Current ³ | I_{SM} | | | | 2.6 | |
| Forward Voltage ¹ | V_{SD} | $I_F = 1A, V_{GS} = 0V$ | | | 1 | V |

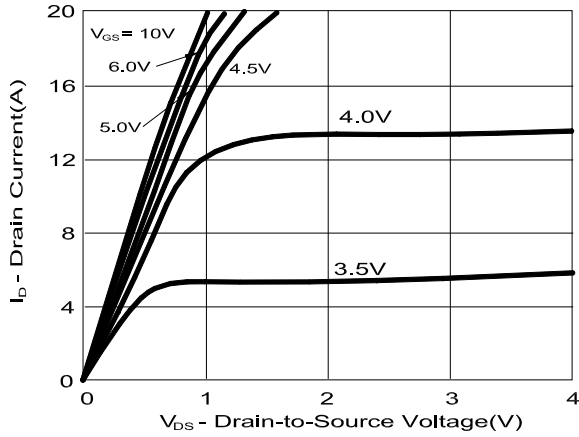
¹Pulse test : Pulse Width $\leq 300 \mu sec$, Duty Cycle $\leq 2\%$.

²Independent of operating temperature.

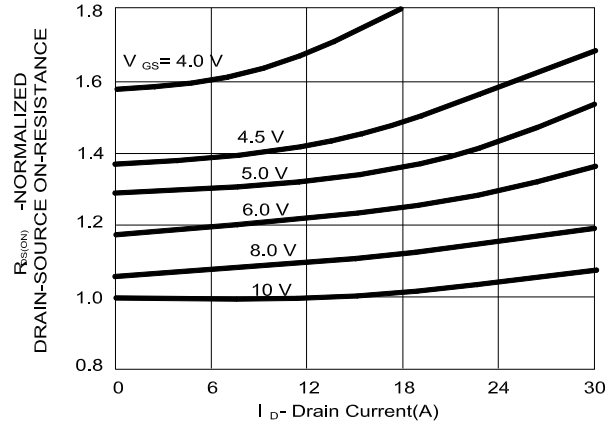
³Pulse width limited by maximum junction temperature.

REMARK: THE PRODUCT MARKED WITH "P5506BDG", DATE CODE or LOT #
Orders for parts with Lead-Free plating can be placed using the PXXXXXXG parts name.

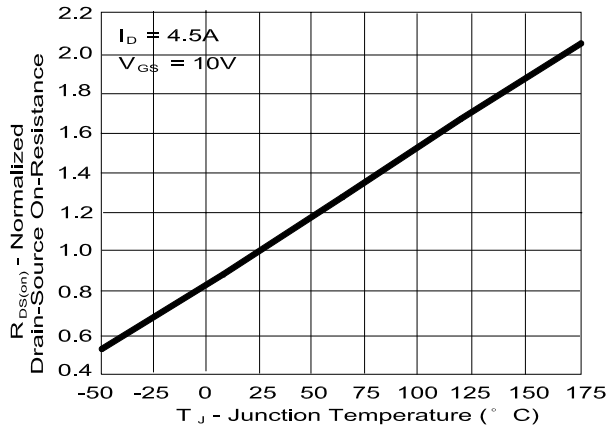
On-Region Characteristics



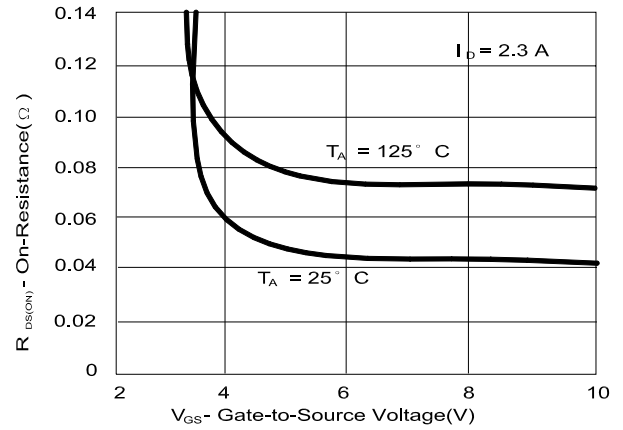
On-Resistance Variation with Drain Current and Gate Voltage



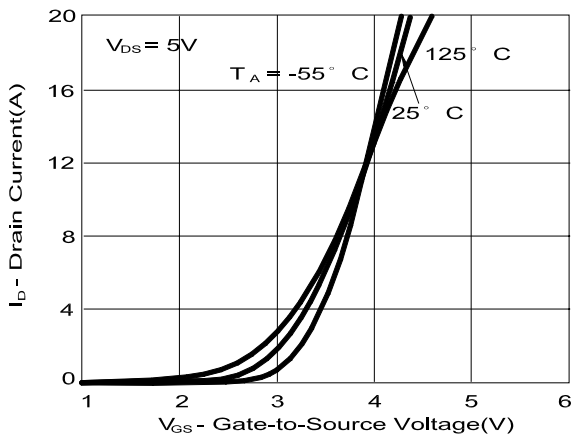
On-Resistance Variation with Temperature



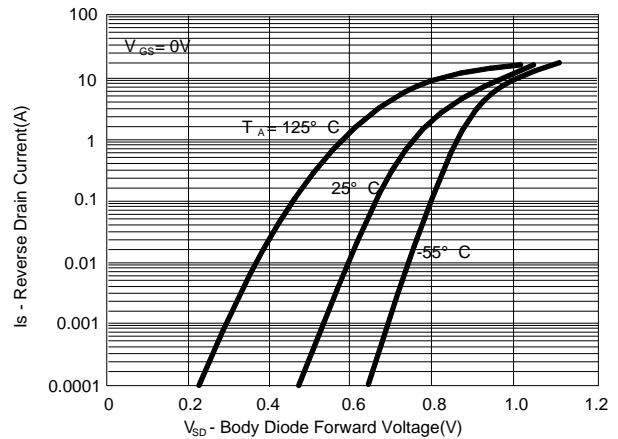
On-Resistance Variation with Gate-to-Source Voltage

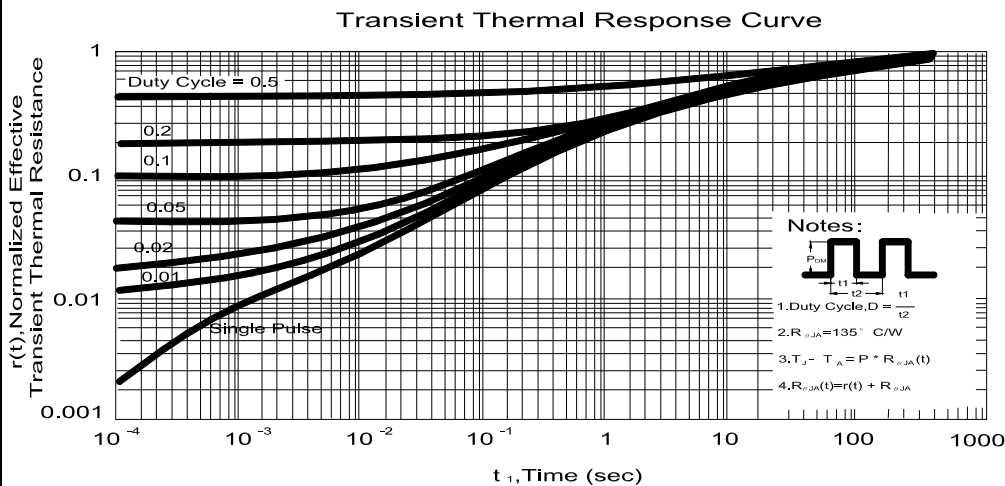
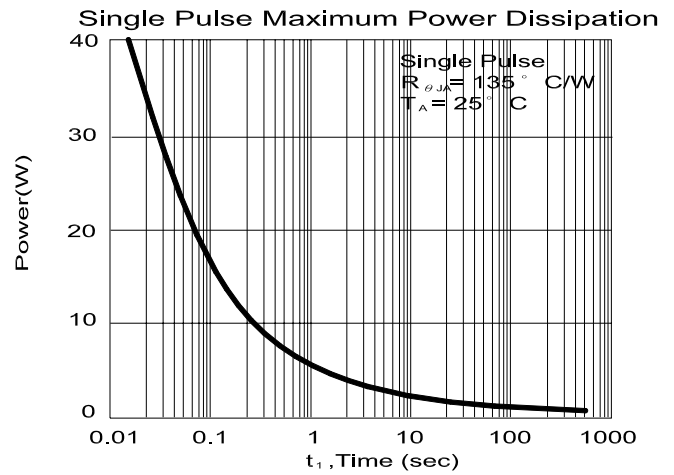
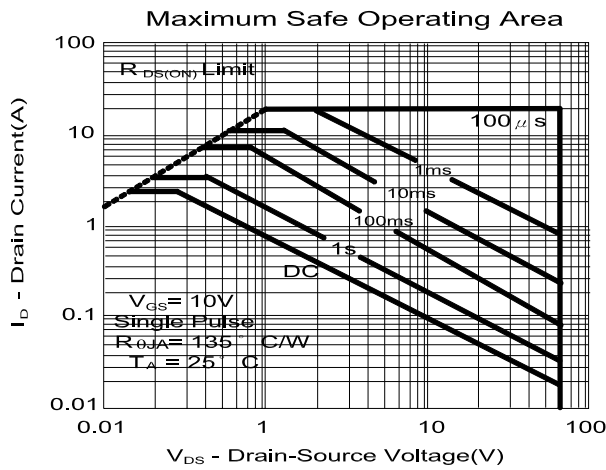
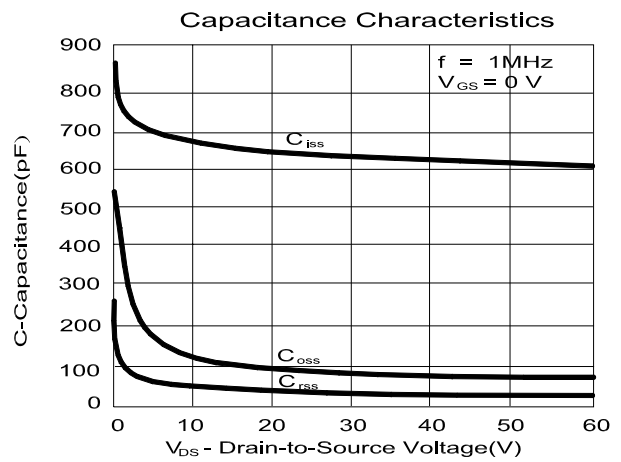
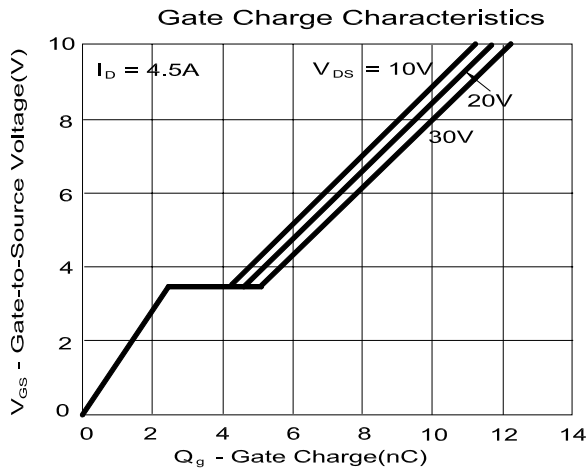


Transfer Characteristics



Body Diode Forward Voltage Variation with Source Current and Temperature





TO-252 (DPAK) MECHANICAL DATA

| Dimension | mm | | | Dimension | mm | | |
|-----------|------|------|------|-----------|------|------|------|
| | Min. | Typ. | Max. | | Min. | Typ. | Max. |
| A | 9.35 | | 10.4 | H | 0.89 | | 2.03 |
| B | 2.2 | | 2.4 | I | 6.35 | | 6.80 |
| C | 0.45 | | 0.6 | J | 5.2 | | 5.5 |
| D | 0.89 | | 1.5 | K | 0.6 | | 1 |
| E | 0.45 | | 0.69 | L | 0.5 | | 0.9 |
| F | 0.03 | | 0.23 | M | 3.96 | 4.57 | 5.18 |
| G | 5.2 | | 6.2 | N | | | |

